NSN 5962-00-301-3457

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View Online at https://aerobasegroup.com/nsn/5962-00-301-3457

Body Length:

Between 0.630 inches and 0.775 inches

Body Width:

Between 0.275 inches and 0.310 inches

Body Height:

Between 0.150 inches and 0.160 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and programmable and programmed and w/open collector

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Gold

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

90.00 nanoseconds propagation delay time, low to high level output and 90.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Precious Material And Location:

Terminal surface gold

Precious Material:

Gold

Test Data Document:

92755-20a3535 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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